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[Vishay Semiconductor/Diodes Division](#)
[VS-42CTQ030STRRPBF](#)

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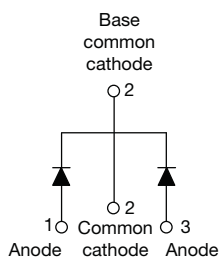
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VS-42CTQ030SPbF, VS-42CTQ030-1PbF

Vishay Semiconductors

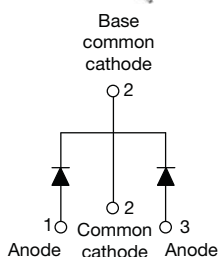
High Performance Schottky Rectifier, 2 x 20 A

TO-263AB (D²PAK)



VS-42CTQ030SPbF

TO-262AA



VS-42CTQ030-1PbF

FEATURES

- 150 °C T_J operation
- Center tap configuration
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
 COMPLIANT
 HALOGEN
 FREE

PRODUCT SUMMARY

Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	2 x 20 A
V _R	30 V
V _F at I _F	0.38 V
I _{RM} max.	183 mA at 125 °C
T _J max.	150 °C
Diode variation	Common cathode
E _{AS}	13

DESCRIPTION

This center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform	40	A
V _{RRM}		30	V
I _{FSM}	t _p = 5 μs sine	1100	A
V _F	20 A _{pk} , T _J = 125 °C (per leg)	0.38	V
T _J	Range	-55 to +150	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-42CTQ030SPbF VS-42CTQ030-1PbF	UNITS
Maximum DC reverse voltage	V _R	30	V
Maximum working peak reverse voltage	V _{RWM}		

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current, see fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 121 °C, rectangular waveform	20	A
			40	
Maximum peak one cycle non-repetitive surge current per leg, see fig. 7	I _{FSM}	5 μs sine or 3 μs rect. pulse	1100	A
		10 ms sine or 6 ms rect. pulse	360	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 2.90 mH	13	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A = 1.5 x V _R typical	3	A



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1	$V_{FM}^{(1)}$	20 A	$T_J = 25\text{ }^\circ\text{C}$	0.48	V
		40 A		0.57	
		20 A	$T_J = 125\text{ }^\circ\text{C}$	0.38	
		40 A		0.51	
Maximum reverse leakage current per leg See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	3	mA
		$T_J = 125\text{ }^\circ\text{C}$		183	
Threshold Voltage	$V_{F(TO)}$	$T_J = T_J \text{ maximum}$		0.22	V
Forward slope resistance	r_f			6.76	m Ω
Maximum junction capacitance per leg	C_T	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^\circ\text{C}$		2840	pF
Typical series inductance per leg	L_S	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s

Note

(1) Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum junction and storage temperature range	T_J, T_{Stg}			-55 to +150	$^\circ\text{C}$	
Maximum thermal resistance, junction to case per leg	R_{thJC}	DC operation		2.0	$^\circ\text{C/W}$	
Maximum thermal resistance, junction to case per package				1.0		
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased		0.50		
Approximate weight					2	g
					0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)	
	maximum			12 (10)		
Marking device			Case style TO-263AB (D ² PAK)	42CTQ030S		
			Case style TO-262AA	42CTQ030-1		



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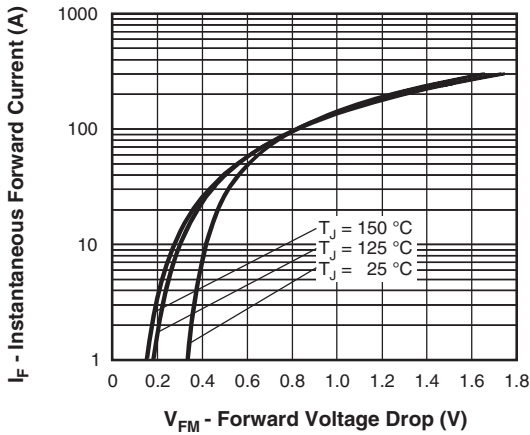


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

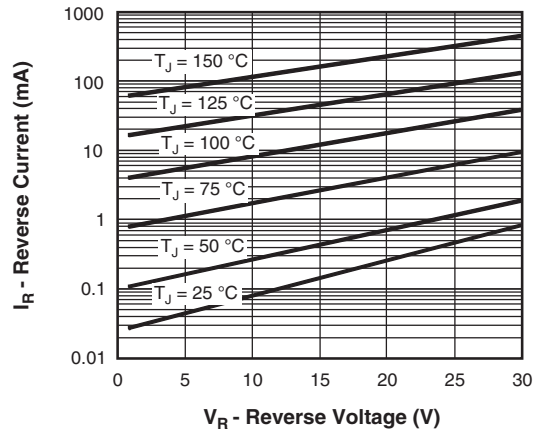


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

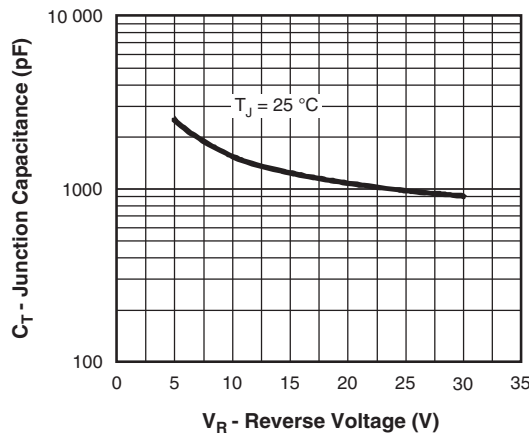


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

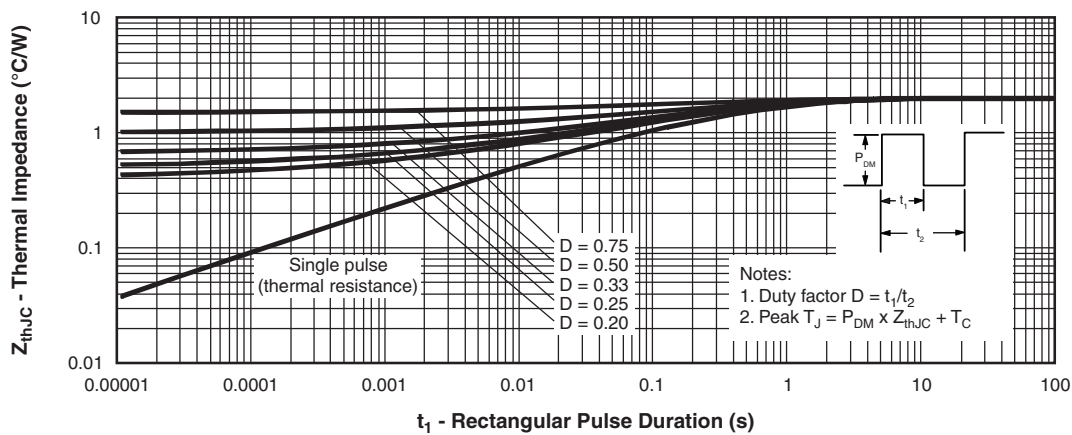


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



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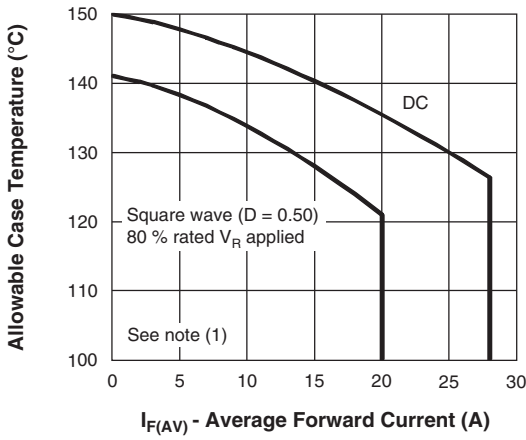


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

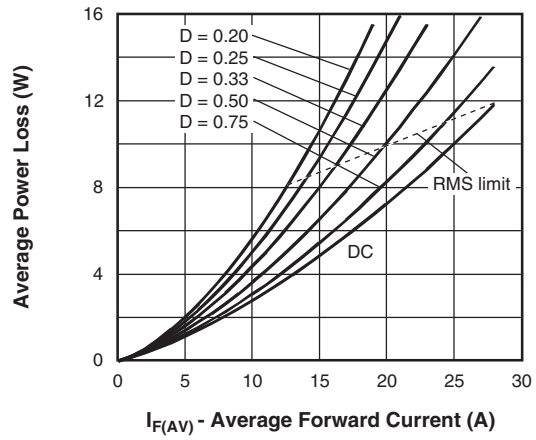


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

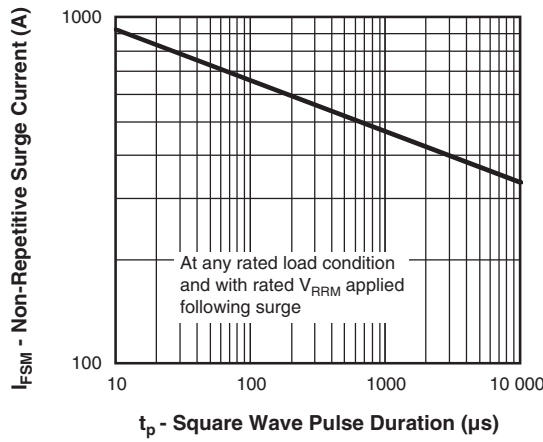


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

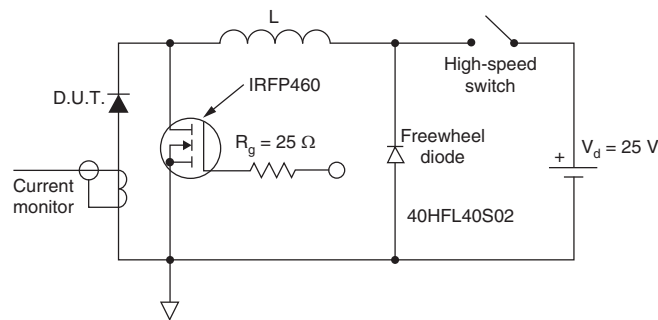


Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
- P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 10 V$



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VS-42CTQ030SPbF, VS-42CTQ030-1PbF

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ORDERING INFORMATION TABLE

Device code	VS-	42	C	T	Q	030	S	TRL	PbF
	①	②	③	④	⑤	⑥	⑦	⑧	⑨

- 1** - Vishay Semiconductors product
- 2** - Current rating (40 A)
- 3** - Circuit configuration: C = common cathode
- 4** - T = TO-220
- 5** - Schottky "Q" series
- 6** - Voltage rating (030 = 30 V)
- 7** -
 - S = D²PAK
 - -1 = TO-262
- 8** -
 - None = tube (50 pieces)
 - TRL = tape and reel (left oriented - for D²PAK only)
 - TRR = tape and reel (right oriented - for D²PAK only)
- 9** - PbF = lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-42CTQ030SPBF	50	1000	Antistatic plastic tubes
VS-42CTQ030STRRPBF	800	800	13" diameter plastic tape and reel
VS-42CTQ030STRLPBF	800	800	13" diameter plastic tape and reel
VS-42CTQ030-1PBF	50	1000	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS		
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046
	TO-262AA	www.vishay.com/doc?95419
Part marking information		www.vishay.com/doc?95008
Packaging information		www.vishay.com/doc?95032



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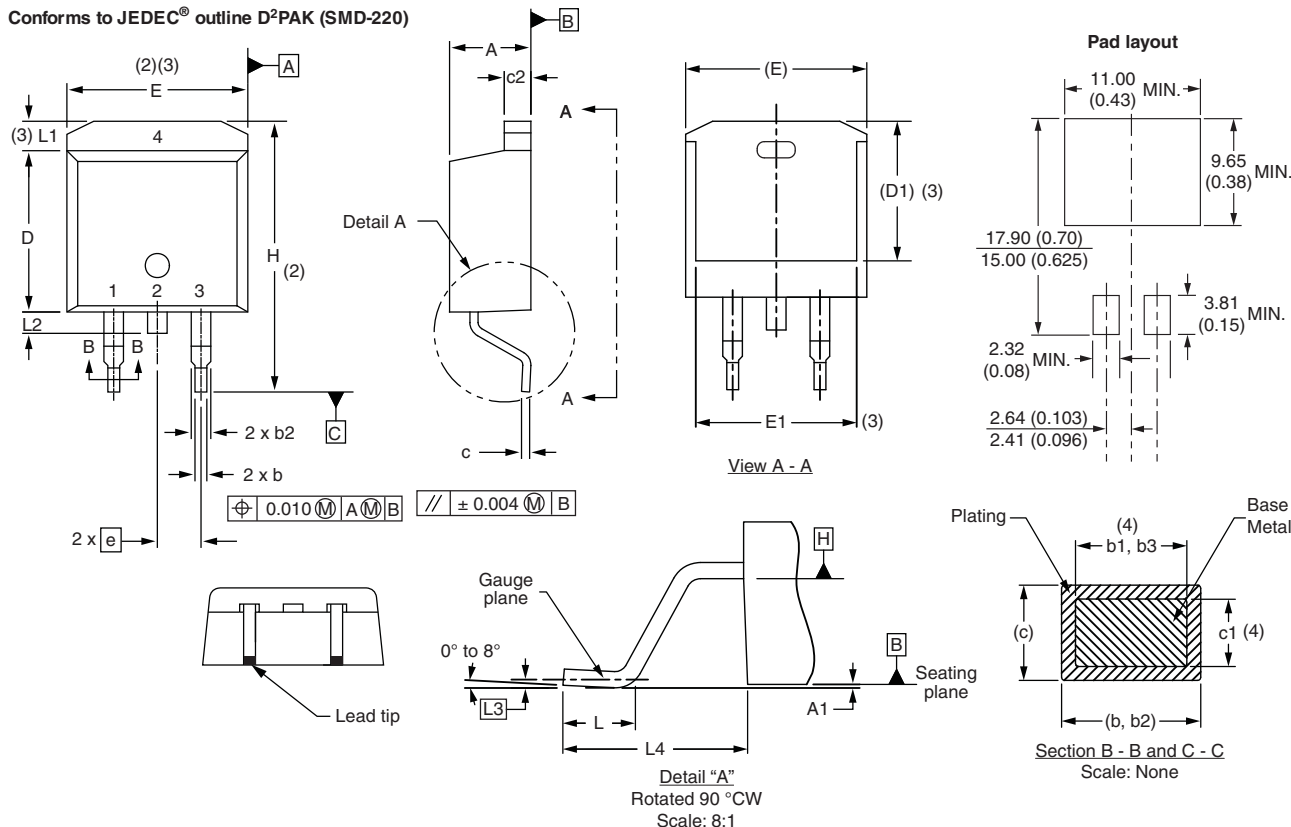
Outline Dimensions

Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches

Conforms to JEDEC® outline D²PAK (SMD-220)



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	e	2.54 BSC		0.100 BSC		
b2	1.14	1.78	0.045	0.070		H	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
c	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25 BSC		0.010 BSC		
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



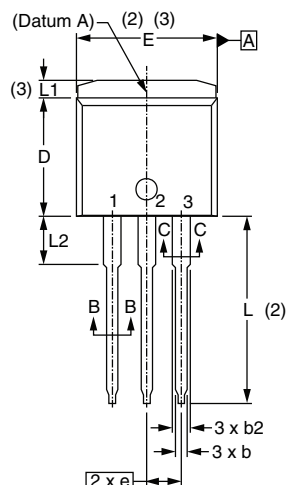
Outline Dimensions

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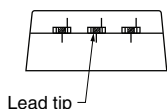
TO-262

DIMENSIONS in millimeters and inches

Modified JEDEC outline TO-262

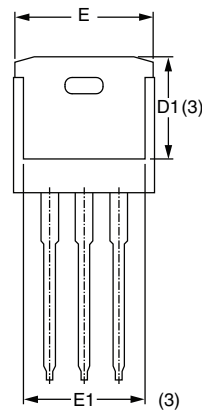
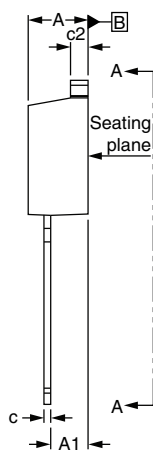


$\oplus 0.010 \text{ (M)} \text{ (A)} \text{ (M)} \text{ (B)}$

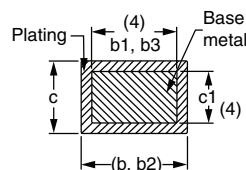


Lead assignments

- Diodes
 1. - Anode (two die)/open (one die)
 2., 4. - Cathode
 3. - Anode



Section A - A



Section B - B and C - C
 Scale: None

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
c	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
e	2.54 BSC		0.100 BSC		
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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